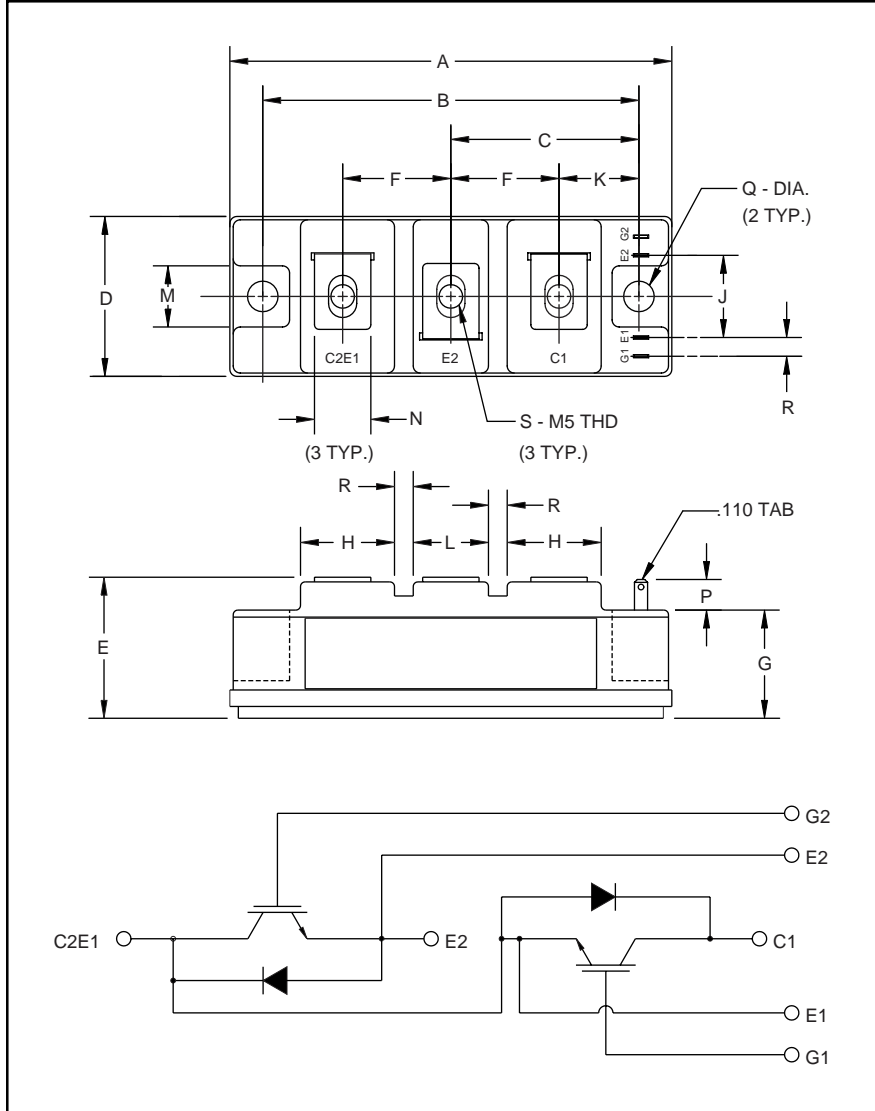


**Authorized Distributor:**  
**Darrah Electric Company**  
**www.darrahelectric.com**

**Dual IGBTMOD™**  
**H-Series Module**  
**100 Amperes/600 Volts**



**Outline Drawing and Circuit Diagram**

Dimensions	Inches	Millimeters
A	3.70	94.0
B	3.150±0.01	80.0±0.25
C	1.57	40.0
D	1.34	34.0
E	1.22 Max.	31.0 Max.
F	0.90	23.0
G	0.85	21.5
H	0.79	20.0
J	0.71	18.0

Dimensions	Inches	Millimeters
K	0.67	17.0
L	0.63	16.0
M	0.51	13.0
N	0.47	12.0
P	0.28	7.0
Q	0.256 Dia.	Dia. 6.5
R	0.16	4.0
S	M5 Metric	M5



**Description:**

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

**Features:**

- Low Drive Power
- Low  $V_{CE(sat)}$
- Discrete Super-Fast Recovery (70ns) Free-Wheel Diode
- High Frequency Operation (20-25kHz)
- Isolated Baseplate for Easy Heat Sinking

**Applications:**

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

**Ordering Information:**

Example: Select the complete part module number you desire from the table below -i.e. CM100DY-12H is a 600V ( $V_{CES}$ ), 100 Ampere Dual IGBTMOD™ Power Module.

Type	Current Rating Amperes	$V_{CES}$ Volts (x 50)
CM	100	12

**CM100DY-12H**  
**Dual IGBTMOD™ H-Series Module**  
 100 Amperes/600 Volts

**Absolute Maximum Ratings,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Ratings	Symbol	CM100DY-12H	Units
Junction Temperature	$T_j$	-40 to 150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	$V_{CES}$	600	Volts
Gate-Emitter Voltage	$V_{GES}$	$\pm 20$	Volts
Collector Current	$I_C$	100	Amperes
Peak Collector Current	$I_{CM}$	200*	Amperes
Diode Forward Current	$I_F$	100	Amperes
Diode Forward Surge Current	$I_{FM}$	200*	Amperes
Power Dissipation	$P_d$	400	Watts
Max. Mounting Torque M5 Terminal Screws	-	17	in-lb
Max. Mounting Torque M6 Mounting Screws	-	26	in-lb
Module Weight (Typical)	-	190	Grams
V Isolation	$V_{RMS}$	2500	Volts

\* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

**Static Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	$I_{CES}$	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	1.0	mA
Gate Leakage Current	$I_{GES}$	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	0.5	$\mu\text{A}$
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C = 10\text{mA}, V_{CE} = 10V$	4.5	6.0	7.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 100A, V_{GE} = 15V$	-	2.1	2.8**	Volts
		$I_C = 100A, V_{GE} = 15V, T_j = 150^\circ\text{C}$	-	2.15	-	Volts
Total Gate Charge	$Q_G$	$V_{CC} = 300V, I_C = 100A, V_{GS} = 15V$	-	300	-	nC
Diode Forward Voltage	$V_{FM}$	$I_E = 100A, V_{GS} = 0V$	-	-	2.8	Volts

\*\* Pulse width and repetition rate should be such that device junction temperature rise is negligible.

**Dynamic Electrical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitance	$C_{ies}$		-	-	10	nF
Output Capacitance	$C_{oes}$	$V_{GE} = 0, V_{CE} = 10V, f = 1\text{MHz}$	-	-	3.5	nF
Reverse Transfer Capacitance	$C_{res}$		-	-	2	nF
Resistive	Turn-on Delay Time	$V_{CC} = 300V, I_C = 100A,$ $V_{GE1} = V_{GE2} = 15V, R_G = 6.3\Omega$	-	-	120	ns
Load	Rise Time					
Switch	Turn-off Delay Time		-	-	200	ns
Times	Fall Time		-	-	300	ns
Diode Reverse Recovery Time	$t_{rr}$	$I_E = 100A, di_E/dt = -200A/\mu\text{s}$	-	-	110	ns
Diode Reverse Recovery Charge	$Q_{rr}$	$I_E = 100A, di_E/dt = -200A/\mu\text{s}$	-	0.27	-	$\mu\text{C}$

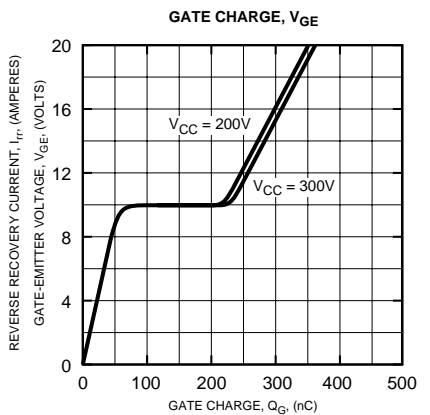
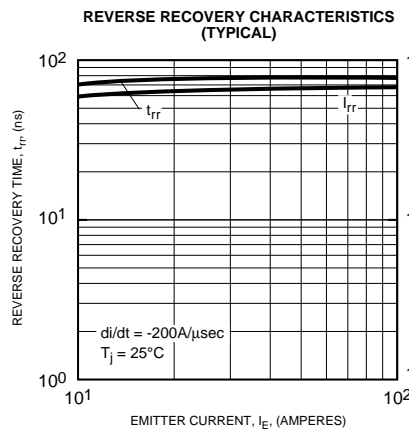
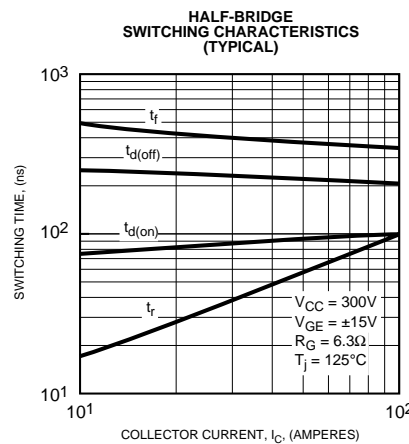
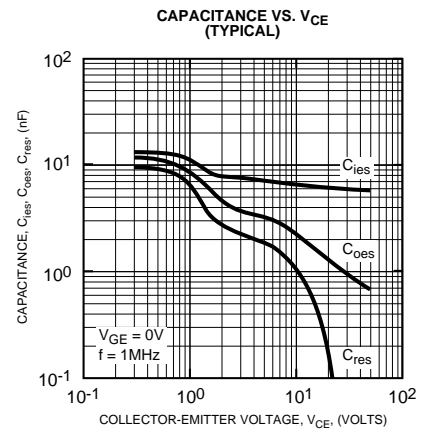
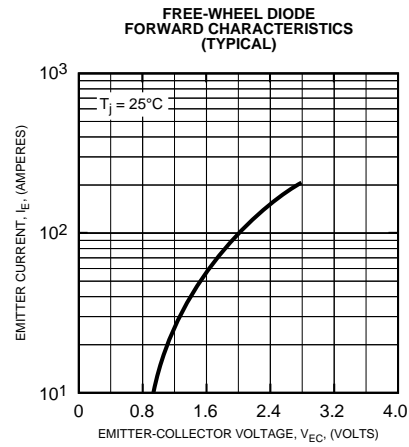
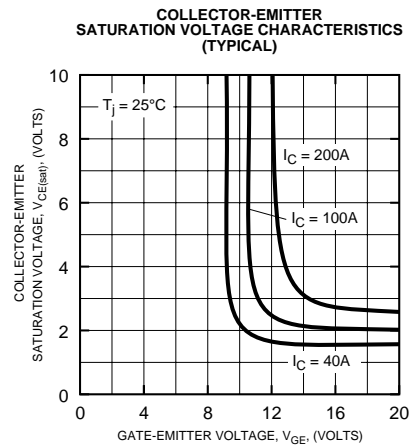
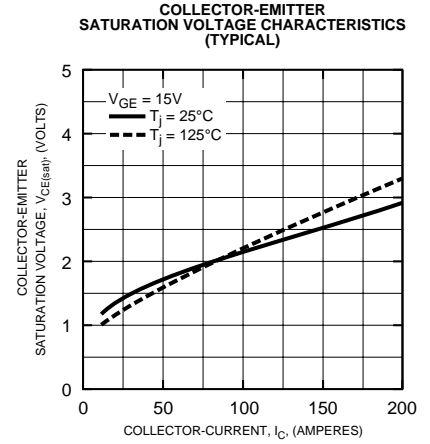
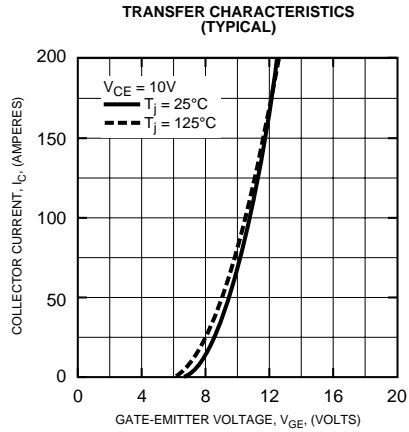
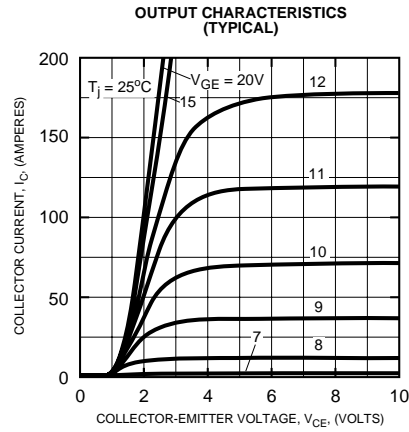
**Thermal and Mechanical Characteristics,  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per IGBT	-	-	0.31	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)}$	Per FWDi	-	-	0.70	$^\circ\text{C/W}$
Contact Thermal Resistance	$R_{th(c-f)}$	Per Module, Thermal Grease Applied	-	-	0.075	$^\circ\text{C/W}$

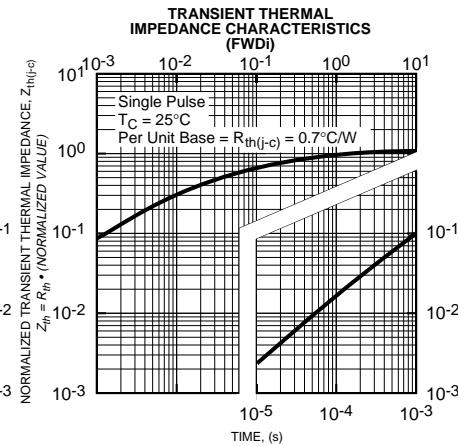
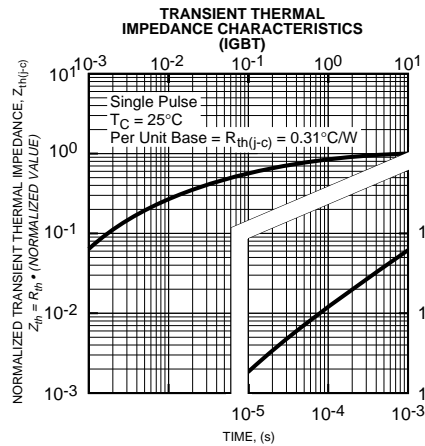


Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

**CM100DY-12H**  
**Dual IGBTMOD™ H-Series Module**  
 100 Amperes/600 Volts



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